

Vishay Siliconix

## Dual P-Channel 30 V (D-S) 175 °C MOSFET

### **DESCRIPTION**

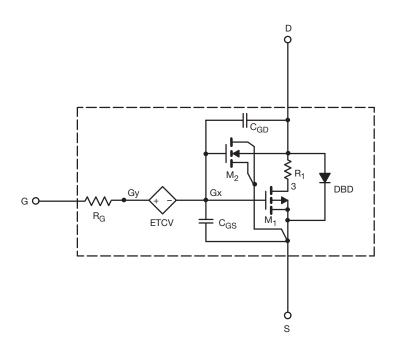
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the -  $55\,^{\circ}$ C to +  $125\,^{\circ}$ C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### **CHARACTERISTICS**

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

### SUBCIRCUIT MODEL SCHEMATIC



### Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



# **SPICE Device Model SQ4937EY**

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SPECIFICATIONS (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	1.9	-	V
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -10 \text{ V}, I_D = -3.9 \text{ A}$	0.056	0.056	Ω
		$V_{GS} = -4.5 \text{ V}, I_D = -2 \text{ A}$	0.118	0.119	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 3.9 A	6	6	S
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = - 3 A	- 0.85	- 0.85	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = - 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	385	384	pF
Output Capacitance	C <sub>oss</sub>		80	84	
Reverse Transfer Capacitance	C <sub>rss</sub>		52	56	
Total Gate Charge	Qg	V <sub>DS</sub> = - 15 V, V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 4.9 A	8	9.5	nC
Gate-Source Charge	Q <sub>gs</sub>		1.7	1.7	
Gate-Drain Charge	Q <sub>gd</sub>		2.3	2.3	

#### Notes

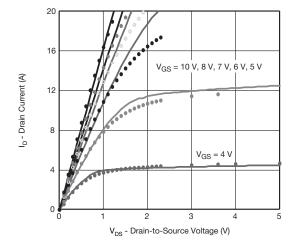
- a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

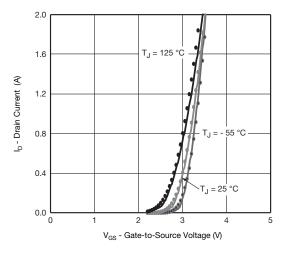


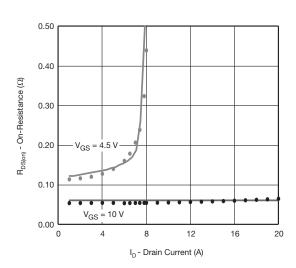
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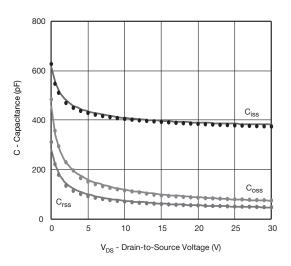
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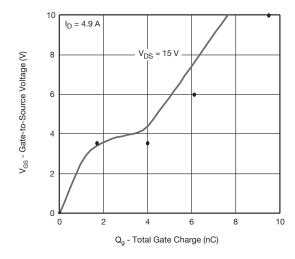
## COMPARISON OF MODEL WITH MEASURED DATA ( $T_J = 25$ °C, unless otherwise noted)

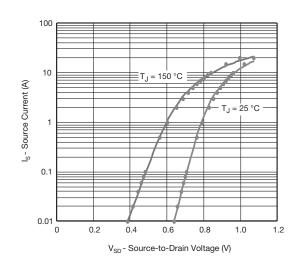












### Note

· Dots and squares represent measured data.



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